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LM4040

Precision Micropower Shunt Voltage Reference

General Description

Ideal for space critical applications, the LM4040 precision voltage reference is available in the sub-miniature SC70 and SOT-23 surface-mount package. The LM4040's advanced design eliminates the need for an external stabilizing capacitor while ensuring stability with any capacitive load, thus making the LM4040 easy to use. Further reducing design effort is the availability of several fixed reverse breakdown voltages: 2.048V, 2.500V, 3.000V, 4.096V, 5.000V, 8.192V, and 10.000V. The minimum operating current increases from 60 μA for the LM4040-2.5 to 100 μA for the LM4040-10.0. All versions have a maximum operating current of 15 mA.

The LM4040 utilizes fuse and zener-zap reverse breakdown voltage trim during wafer sort to ensure that the prime parts have an accuracy of better than $\pm 0.1\%$ (A grade) at $25^{\circ}\text{C}.$ Bandgap reference temperature drift curvature correction and low dynamic impedance ensure stable reverse breakdown voltage accuracy over a wide range of operating temperatures and currents.

Also available is the LM4041 with two reverse breakdown voltage versions: adjustable and 1.2V. Please see the LM4041 data sheet.

Features

- Small packages: SOT-23, TO-92 and SC70
- No output capacitor required
- Tolerates capacitive loads
- Fixed reverse breakdown voltages of 2.048V, 2.500V, 3.000V, 4.096V, 5.000V, 8.192V, and 10.000V

Key Specifications (LM4040-2.5)

Output voltage tolerance

(A grade, 25°C) ±0.1% (max)

Low output noise (10 Hz to 10 kHz)

 $35 \mu V_{rms}(typ)$

(10 Hz to 10 kHz)
■ Wide operating current range

60 μA to 15 mA

■ Industrial temperature range

–40°C to +85°C

Extended temperature range

-40°C to +125°C

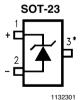
■ Low temperature coefficient

100 ppm/°C (max)

Applications

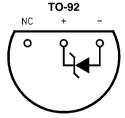
- Portable, Battery-Powered Equipment
- Data Acquisition Systems
- Instrumentation
- Process Control
- Energy Management
- Product Testing
- Automotive
- Precision Audio Components

Connection Diagrams

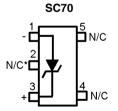


*This pin must be left floating or connected to pin 2.

Top View See NS Package Number MF03A (JEDEC Registration TO-236AB)



Bottom View
See NS Package Number Z03A



1132330

*This pin must be left floating or connected to pin 1.

Top View
See NS Package Number MAA05A

Ordering Information Industrial Temperature Range (-40°C to +85°C)

Reverse			Package			
Breakdown	M3 (S	OT-23)	M7 (S	SC70)		
Voltage Tolerance at 25°C and Average Reverse Breakdown Voltage Temperature Coefficient	Supplied as 1000 Units Tape and Reel	Supplied as 3000 Units tape and Reel	Supplied as 1000 Units Tape and Reel	Supplied as 3000 Units Tape and Reel	Z (TO-92)	NS Package Number
±0.1%, 100 ppm/°	LM4040AIM3-2.0	LM4040AIM3X-2.0			LM4040AIZ-2.0	MF03A,
C max (A grade)	LM4040AIM3-2.5 LM4040AIM3-3.0 LM4040AIM3-4.1	LM4040AIM3X-2.5 LM4040AIM3X-3.0 LM4040AIM3X-4.1			LM4040AIZ-2.5 LM4040AIZ-3.0 LM4040AIZ-4.1	Z03A
	LM4040AIM3-5.0 LM4040AIM3-8.2 LM4040AIM3-10.0	LM4040AIM3X-5.0 LM4040AIM3X-8.2 LM4040AIM3X-10.			LM4040AIZ-5.0 LM4040AIZ-8.2 LM4040AIZ-10.0	
±0.2%, 100 ppm/° C max (B grade)	LM4040BIM3-2.0 LM4040BIM3-2.5 LM4040BIM3-3.0	0 LM4040BIM3X-2.0 LM4040BIM3X-2.5 LM4040BIM3X-3.0	LM4040BIM7-2.0 LM4040BIM7-2.5 LM4040BIM7-3.0	LM4040BIM7X-2.0 LM4040BIM7X-2.5 LM4040BIM7X-3.0	LM4040BIZ-2.0 LM4040BIZ-2.5 LM4040BIZ-3.0	MF03A, Z03A, MAA05A
	LM4040BIM3-4.1 LM4040BIM3-5.0 LM4040BIM3-8.2 LM4040BIM3-10.0	LM4040BIM3X-4.1 LM4040BIM3X-5.0 LM4040BIM3X-8.2 LM4040BIM3X-10.	LM4040BIM7-4.1 LM4040BIM7-5.0	LM4040BIM7X-4.1 LM4040BIM7X-5.0	LM4040BIZ-4.1 LM4040BIZ-5.0 LM4040BIZ-8.2 LM4040BIZ-10.0	
±0.5%, 100 ppm/°	LM4040CIM3-2.0	LM4040CIM3X-2.0	LM4040CIM7-2.0	LM4040CIM7X-2.0	LM4040CIZ-2.0	MF03A,
C max (C grade)	LM4040CIM3-2.5 LM4040CIM3-3.0 LM4040CIM3-4.1 LM4040CIM3-5.0 LM4040CIM3-8.2 LM4040CIM3-10.0	LM4040CIM3X-2.5 LM4040CIM3X-3.0 LM4040CIM3X-4.1 LM4040CIM3X-5.0 LM4040CIM3X-8.2 LM4040CIM3X-10.	LM4040CIM7-2.5 LM4040CIM7-3.0 LM4040CIM7-4.1 LM4040CIM7-5.0	LM4040CIM7X-2.5 LM4040CIM7X-3.0 LM4040CIM7X-4.1 LM4040CIM7X-5.0	LM4040CIZ-2.5 LM4040CIZ-3.0 LM4040CIZ-4.1 LM4040CIZ-5.0 LM4040CIZ-8.2 LM4040CIZ-10.0	Z03A, MAA05A
±1.0%, 150 ppm/° C max (D grade)	LM4040DIM3-2.0 LM4040DIM3-2.5 LM4040DIM3-3.0 LM4040DIM3-4.1 LM4040DIM3-5.0 LM4040DIM3-8.2 LM4040DIM3-10.0	LM4040DIM3X-2.0 LM4040DIM3X-2.5 LM4040DIM3X-3.0 LM4040DIM3X-4.1 LM4040DIM3X-5.0 LM4040DIM3X-8.2 LM4040DIM3X-10.	LM4040DIM7-2.0 LM4040DIM7-2.5 LM4040DIM7-3.0 LM4040DIM7-4.1 LM4040DIM7-5.0	LM4040DIM7X-2.0 LM4040DIM7X-2.5 LM4040DIM7X-3.0 LM4040DIM7X-4.1 LM4040DIM7X-5.0	LM4040DIZ-2.0 LM4040DIZ-2.5 LM4040DIZ-3.0 LM4040DIZ-4.1 LM4040DIZ-5.0 LM4040DIZ-8.2 LM4040DIZ-10.0	MF03A, Z03A, MAA05A
±2.0%, 150 ppm/°	LM4040EIM3-2.0	LM4040EIM3X-2.0	LM4040EIM7-2.0	LM4040EIM7X-2.0	LM4040EIZ-2.0	MF03A,
C max (E grade)	LM4040EIM3-2.5 LM4040EIM3-3.0	LM4040EIM3X-2.5 LM4040EIM3X-3.0	LM4040EIM7-2.5 LM4040EIM7-3.0	LM4040EIM7X-2.5 LM4040EIM7X-3.0	LM4040EIZ-2.5 LM4040EIZ-3.0	Z03A, MAA05A

Extended Temperature Range (-40 °C to +125°C)

Reverse Breakdown Voltage Tolerance at 25 °C and Average Reverse Breakdown Voltage Temperature Coefficient	Package M3 (SOT-23) See NS Package Number MF03A
±0.5%, 100 ppm/°C max (C grade)	LM4040CEM3-2.0, LM4040CEM3-2.5, LM4040CEM3-3.0, LM4040CEM3-5.0
±1.0%, 150 ppm/°C max (D grade)	LM4040DEM3-2.0, LM4040DEM3-2.5, LM4040DEM3-3.0, LM4040DEM3-5.0
±2.0%, 150 ppm/°C max (E grade)	LM4040EEM3-2.0, LM4040EEM3-2.5, LM4040EEM3-3.0

SOT-23 AND SC70 Package Marking Information

Only three fields of marking are possible on the SOT-23's and SC70's small surface. This table gives the meaning of the three fields

Part Marking	Field Definition
RJA SOT-23 only	First Field:
R2A SOT-23 only	
RKA SOT-23 only	
R4A SOT-23 only	R = Reference
R5A SOT-23 only	Second Field:
	J = 2.048V Voltage Option
	2 = 2.500V Voltage Option
R8A SOT-23 only	K = 3.000V Voltage Option
R0A SOT-23 only	4 = 4.096V Voltage Option
RJB	
R2B	5 = 5.000V Voltage Option
RKB	
R4B	8= 8.192V Voltage Option
R5B	0 = 10.000V Voltage Option
R8B SOT-23 only	
R0B SOT-23 only	Third Field:
RJC	
R2C	A-E = Initial Reverse Breakdown Voltage or Reference Voltage Tolerance
RKC	
R4C	$A = \pm 0.1\%$, $B = \pm 0.2\%$, $C = +0.5\%$, $D = \pm 1.0\%$, $E = \pm 2.0\%$
R5C	
R8C SOT-23 only	
R0C SOT-23 only	
RJD	
R2D	
RKD	
R4D	
R5D	
R8D SOT-23 only	
R0D SOT-23 only	
RJE	
R2E	
RKE	

200V

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Reverse Current 20 mA Forward Current 10 mA Power Dissipation ($T_A = 25^{\circ}C$) (*Note 2*) M3 Package 306 mW Z Package 550 mW M7 Package 241 mW Storage Temperature -65°C to +150°C Lead Temperature M3 Package Vapor phase (60 seconds) +215°C Infrared (15 seconds) +220°C Z Package Soldering (10 seconds) +260°C **ESD Susceptibility** Human Body Model (Note 3) 2 kV Machine Model (Note 3)

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Operating Ratings (Note 1, Note 2)

$(T_{min} \le T_A \le T_{max})$
$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$
-40 °C \leq T _A \leq $+125$ °C
60 μA to 15 mA
60 μA to 15 mA
62 µA to 15 mA
68 μA to 15 mA
74 μA to 15 mA
91 μA to 15 mA
100 μA to 15 mA

LM4040-2.0

Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}; all other limits T_A = T_J = 25°C. The grades A and B designate initial Reverse Breakdown Voltage tolerances of $\pm 0.1\%$ and $\pm 0.2\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040AIM3 LM4040AIZ (Limit) (Note 5)	LM4040BIM3 LM4040BIZ LM4040BIM7 (Limit) (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 100 μA	2.048			V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	Ι _R = 100 μΑ		±2.0 ±15	±4.1 ±17	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45			μΑ
				60	60	μA (max)
				65	65	μA (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown	I _R = 10 mA	±20			ppm/°C
	Voltage Temperature	I _R = 1 mA	±15	±100	±100	ppm/°C (max)
	Coefficient (Note 6)	I _R = 100 μA	±15			ppm/°C
$\Delta V_R/\Delta I_R$	Reverse Breakdown Voltage	$I_{RMIN} \le I_{R} \le 1 \text{ mA}$	0.3			mV
	Change with Operating			0.8	0.8	mV (max)
	Current Change (Note)			1.0	1.0	mV (max)
		1 mA ≤ I _R ≤ 15 mA	2.5			mV
				6.0	6.0	mV (max)
				8.0	8.0	mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz, I _{AC} =	0.3			Ω
		0.1 I _R		0.8	0.8	Ω (max)
e _N	Wideband Noise	I _R = 100 μA	35			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040AIM3 LM4040AIZ (Limit) (Note 5)	LM4040BIM3 LM4040BIZ LM4040BIM7 (Limit) (Note 5)	Units (Limit)
ΔV_R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C I _R = 100 µA	120			ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C$ to $+125^{\circ}C$	0.08			%

LM4040-2.0

Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C, D and E designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$, $\pm 1.0\%$ and $\pm 2.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CIM3 LM4040CIZ LM4040CIM7 (Limit) (Note 5)	LM4040DIM3 LM4040DIZ LM4040DIM7 (Limit) (Note 5)	LM4040EIM7 LM4040EIZ (Limit) (Note 5)	Units (Limit)
V_R	Reverse Breakdown Voltage	Ι _R = 100 μΑ	2.048				V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	Ι _R = 100 μΑ		±10 ±23	±20 ±40	±41 ±60	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45	60 65	65 70	65 70	μΑ μΑ (max) μΑ (max)
$\Delta V_R / \Delta T$	Average Reverse Breakdown Voltage Temperature Coefficient (Note 6)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu\text{A}$	±20 ±15 ±15	±100	±150	±150	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current	$I_{\text{RMIN}} \le I_{\text{R}} \le 1 \text{ mA}$	0.3	0.8 1.0	1.0 1.2	1.0 1.2	mV mV (max) mV (max)
	Change (Note)	1 mA ≤ I _R ≤ 15 mA	2.5	6.0 8.0	8.0 10.0	8.0 10.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz I _{AC} = 0.1 I _R	0.3	0.9	1.1	1.1	Ω Ω(max)
e _N	Wideband Noise	$I_R = 100 \mu\text{A}$ 10 Hz \le f \le 10 kHz	35				μV_{rms}
ΔV _R	Voltage Long Term	t = 1000 hrs $T = 25^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$ $I_R = 100 \mu\text{A}$	120				ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C \text{ to } +125^{\circ}C$	0.08				%

LM4040-2.0

Electrical Characteristics (Extended Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C, D and E designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$, $\pm 1.0\%$ and $\pm 2.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	3 (Limit) (<i>Note 5</i>)	3 (Limit) (<i>Note 5</i>)	LM4040EEM3 (Limit) (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	Ι _R = 100 μΑ	2.048				V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	Ι _R = 100 μΑ		±10 ±30	±20 ± 50	±41 ±70	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45	60 68	65 73	65 73	μΑ μΑ (max) μΑ (max)
ΔV _R /ΔΤ	Average Reverse Breakdown Voltage Temperature Coefficient (Note 6)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu\text{A}$	±20 ±15 ±15	±100	±150	±150	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (Note 7)	I _{RMIN} ≤ I _R ≤ 1 mA	0.3	0.8 1.0	1.0 1.2	1.0 1.2	mV mV (max) mV (max)
		1 mA ≤ I _R ≤ 15 mA	2.5	6.0 8.0	8.0 10.0	8.0 10.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz, I _{AC} = 0.1 I _R	0.3	0.9	1.1	1.1	Ω Ω (max)
e _N	Wideband Noise	$I_R = 100 \mu A$ 10 Hz \le f \le 10 kHz	35				μV_{rms}
ΔV_R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C I _R = 100 μA	120				ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C \text{ to } +125^{\circ}C$	0.08				%

LM4040-2.5 Electrical Characteristics (Industrial Temperature Range) Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades A and B designate initial Reverse Breakdown Voltage tolerances of ±0.1% and ±0.2%, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040AIM3 LM4040AIZ (Limit) (Note 5)	LM4040BIM3 LM4040BIZ LM4040BIM7 Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 100 μA	2.500			V
	Reverse Breakdown Voltage	I _R = 100 μA		±2.5	±5.0	mV (max)
	Tolerance (Note 6)			±19	±21	mV (max)
I _{RMIN}	Minimum Operating Current		45			μΑ
				60	60	μA (max)
				65	65	μA (max)
$\Delta V_R / \Delta T$	Average Reverse Breakdown	I _R = 10 mA	±20			ppm/°C
	Voltage Temperature	I _R = 1 mA	±15	±100	±100	ppm/°C (max)
	Coefficient (Note 6)	I _R = 100 μA	±15			ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage	I _{RMIN} ≤ I _R ≤ 1 mA	0.3			mV
	Change with Operating			0.8	0.8	mV (max)
	Current Change (Note 7)			1.0	1.0	mV (max)
		1 mA ≤ I _R ≤ 15 mA	2.5			mV
				6.0	6.0	mV (max)
				8.0	8.0	mV (max)
Z_R	Reverse Dynamic Impedance		0.3			Ω
		0.1 I _R		0.8	0.8	Ω (max)
e _N	Wideband Noise	I _R = 100 μA	35			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				
ΔV _R	Reverse Breakdown Voltage	t = 1000 hrs				
	Long Term Stability	T = 25°C ±0.1°C	120			ppm
		I _R = 100 μA				
V _{HYST}	Thermal Hysteresis (<i>Note 8</i>)	$\Delta T = -40$ °C to +125°C	0.08			%

LM4040-2.5 Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C, D and E designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$, $\pm 1.0\%$ and $\pm 2.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CIM3 LM4040CIZ LM4040CIM7 Limits (Note 5)	LM4040DIM3 LM4040DIZ LM4040DIM7 Limits (Note 5)	LM4040EIM7 LM4040EIZ Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	Ι _R = 100 μΑ	2.500				V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	Ι _R = 100 μΑ		±12 ±29	±25 ±49	±50 ±74	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45	60 65	65 70	65 70	μΑ μΑ (max) μΑ (max)
ΔV _R /ΔT	Average Reverse Breakdown Voltage Temperature Coefficient(Note 6)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu\text{A}$	±20 ±15 ±15	±100	±150	±150	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current	I _{RMIN} ≤ I _R ≤ 1 mA	0.3	0.8 1.0	1.0 1.2	1.0 1.2	mV mV (max) mV (max)
	Change (Note 7)	1 mA ≤ I _R ≤ 15 mA	2.5	6.0 8.0	8.0 10.0	8.0 10.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz I _{AC} = 0.1 I _R	0.3	0.9	1.1	1.1	Ω Ω(max)
e _N	Wideband Noise	I _R = 100 μA 10 Hz ≤ f ≤ 10 kHz	35				μV_{rms}
ΔV_R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C I _R = 100 μA	120				ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ} \text{C to } +125^{\circ} \text{C}$	0.08				%

LM4040-2.5 Electrical Characteristics (Extended Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C, D and E designate initial Reverse Breakdown Voltage tolerances of ±0.5%, ±1.0% and ±2.0%, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CEM 3 Limits (Note 5)	LM4040DEM 3 Limits (<i>Note 5</i>)	LM4040EEM3 Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	Ι _R = 100 μΑ	2.500				V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	Ι _R = 100 μΑ		±12 ±38	±25 ± 63	±50 ±88	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45	60 68	65 73	65 73	μΑ μΑ (max) μΑ (max)
ΔV _R /ΔΤ	Average Reverse Breakdown Voltage Temperature Coefficient (Note 6)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu\text{A}$	±20 ±15 ±15	±100	±150	±150	ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (Note 7)	I _{RMIN} ≤ I _R ≤ 1 mA	0.3	0.8 1.0	1.0 1.2	1.0 1.2	mV mV (max) mV (max)
		1 mA ≤ I _R ≤ 15 mA	2.5	6.0 8.0	8.0 10.0	8.0 10.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz, I _{AC} = 0.1 I _R	0.3	0.9	1.1	1.1	Ω Ω (max)
e _N	Wideband Noise	$I_{R} = 100 \mu\text{A}$ 10 Hz \le f \le 10 kHz	35				μV_{rms}
ΔV _R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C I _R = 100 μA	120				ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C \text{ to } +125^{\circ}C$	0.08				%

LM4040-3.0 Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}; all other limits T_A = T_J = 25°C. The grades A and B designate initial Reverse Breakdown Voltage tolerances of $\pm 0.1\%$ and $\pm 0.2\%$, respectively.

Symbol	Parameter	Conditions	Typical (<i>Note 4</i>)	LM4040AIM3 LM4040AIZ (Limit) (<i>Note 5</i>)	LM4040BIM3 LM4040BIZ LM4040BIM7 Limits (Note 5)	Units (Limit)
V_R	Reverse Breakdown Voltage	I _R = 100 μA	3.000			V
	Reverse Breakdown Voltage	I _R = 100 μA		±3.0	±6.0	mV (max)
	Tolerance (Note 6)			±22	±26	mV (max)
I _{RMIN}	Minimum Operating Current		47			μΑ
				62	62	μA (max)
				67	67	μA (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown	I _R = 10 mA	±20			ppm/°C
	Voltage Temperature	I _R = 1 mA	±15	±100	±100	ppm/°C (max)
	Coefficient (Note 6)	I _R = 100 μA	±15			ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage	$I_{RMIN} \le I_{R} \le 1 \text{ mA}$	0.6			mV
	Change with Operating			0.8	0.8	mV (max)
	Current Change (Note 7)			1.1	1.1	mV (max)
		1 mA ≤ I _R ≤ 15 mA	2.7			mV
				6.0	6.0	mV (max)
				9.0	9.0	mV (max)
Z_R	Reverse Dynamic Impedance	$I_R = 1 \text{ mA, f} = 120 \text{ Hz, } I_{AC} =$	0.4			Ω
		0.1 I _R		0.9	0.9	Ω (max)
e _N	Wideband Noise	I _R = 100 μA	35			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				
ΔV _R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C I _R = 100 μA	120			ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C \text{ to } +125^{\circ}C$	0.08			%

LM4040-3.0 Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C, D and E designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$, $\pm 1.0\%$ and $\pm 2.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CIM3 LM4040CIZ LM4040CIM7 Limits (Note 5)	LM4040DIM3 LM4040DIZ LM4040DIM7 Limits (Note 5)	LM4040EIM7 LM4040EIZ Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	Ι _R = 100 μΑ	3.000				V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	Ι _R = 100 μΑ		±15 ±34	±30 ± 59	±60 ± 89	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		45	60 65	65 70	65 70	μΑ μΑ (max) μΑ (max)
$\Delta V_R / \Delta T$	Average Reverse Breakdown Voltage Temperature Coefficient(Note 6)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu\text{A}$	±20 ±15 ±15	±100	±150	±150	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current	I _{RMIN} ≤ I _R ≤ 1 mA	0.4	0.8 1.1	1.1 1.3	1.1 1.3	mV mV (max) mV (max)
	Change (Note 7)	1 mA ≤ I _R ≤ 15 mA	2.7	6.0 9.0	8.0 11.0	8.0 11.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz I _{AC} = 0.1 I _R	0.4	0.9	1.2	1.2	Ω Ω(max)
e _N	Wideband Noise	I _R = 100 μA 10 Hz ≤ f ≤ 10 kHz	35				μV_{rms}
ΔV _R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C I _R = 100 µA	120				ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ} \text{C to } +125^{\circ} \text{C}$	0.08				%

LM4040-3.0 Electrical Characteristics (Extended Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C, D and E designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$, $\pm 1.0\%$ and $\pm 2.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CEM 3 Limits (Note 5)	3 Limits (<i>Note 5</i>)	LM4040EEM3 Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	Ι _R = 100 μΑ	3.000				V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	Ι _R = 100 μΑ		±15 ± 45	±30 ± 75	±60 ±105	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		47	62 70	67 75	67 75	μΑ μΑ (max) μΑ (max)
ΔV _R /ΔT	Average Reverse Breakdown Voltage Temperature Coefficient (<i>Note 6</i>)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu\text{A}$	±20 ±15 ±15	±100	±150	±150	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (Note 7)	I _{RMIN} ≤ I _R ≤ 1 mA	0.4	0.8 1.1	1.1	1.1 1.3	mV mV (max) mV (max)
		1 mA ≤ I _R ≤ 15 mA	2.7	6.0 9.0	8.0 11.0	8.0 11.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz, I _{AC} = 0.1 I _R	0.4	0.9	1.2	1.2	Ω Ω (max)
e _N	Wideband Noise	I _R = 100 μA 10 Hz ≤ f ≤ 10 kHz	35				μV_{rms}
ΔV_R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C I _R = 100 μA	120				ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C \text{ to } +125^{\circ}C$	0.08				%

LM4040-4.1

Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades A and B designate initial Reverse Breakdown Voltage tolerances of ±0.1% and ±0.2%, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040AIM3 LM4040AIZ Limits (Note 5)	LM4040BIM3 LM4040BIZ LM4040BIM7 Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 100 μA	4.096			V
	Reverse Breakdown Voltage	I _R = 100 μA		±4.1	±8.2	mV (max)
	Tolerance (Note 6)			±31	±35	mV (max)
I _{RMIN}	Minimum Operating Current		50			μΑ
				68	68	μA (max)
				73	73	μA (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown	I _R = 10 mA	±30			ppm/°C
	Voltage Temperature Coefficient(Note 6)	I _R = 1 mA	±20	±100	±100	ppm/°C (max)
		I _R = 100 μA	±20			ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating	I _{RMIN} ≤ I _R ≤ 1 mA	0.5			mV
				0.9	0.9	mV (max)
	Current Change (Note 7)			1.2	1.2	mV (max)
		1 mA ≤ I _R ≤ 15 mA	3.0			mV
				7.0	7.0	mV (max)
				10.0	10.0	mV (max)
Z_R	Reverse Dynamic Impedance	$I_R = 1 \text{ mA, f} = 120 \text{ Hz,}$	0.5			Ω
		$I_{AC} = 0.1 I_{R}$		1.0	1.0	Ω (max)
e_N	Wideband Noise	I _R = 100 μA	80			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				
ΔV_R	1	t = 1000 hrs	120			ppm
	Long Term Stability	T = 25°C ±0.1°C				
		I _R = 100 μA	1			
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C$ to $+125^{\circ}C$	0.08			%

LM4040-4.1 Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}; all other limits T_A = T_J = 25°C. The grades C and D designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$ and $\pm 1.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CIM3 LM4040CIZ LM4040CIM7 Limits (Note 5)	LM4040DIM3 LM4040DIZ LM4040DIM7 Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _B = 100 μA	4.096	(,	(2.2.2)	V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	I _R = 100 μA		±20 ±47	±41 ±81	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		50	68 73	73 78	μΑ μΑ (max) μΑ (max)
$\Delta V_R / \Delta T$	Average Reverse Breakdown Voltage Temperature Coefficient (<i>Note 6</i>)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu\text{A}$	±30 ±20 ±20	±100	±150	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (<i>Note 7</i>)	$I_{RMIN} \le I_R \le 1 \text{ mA}$ $1 \text{ mA} \le I_R \le 15 \text{ mA}$	3.0	0.9 1.2 7.0	1.2 1.5	mV mV (max) mV (max) mV mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz, I _{AC} = 0.1 I _R	0.5	10.0	13.0	mV (max) Ω Ω (max)
e _N	Wideband Noise	$I_R = 100 \mu\text{A}$ $10 \text{Hz} \le f \le 10 \text{kHz}$	80			μV_{rms}
ΔV _R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C I _R = 100 µA	120			ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C$ to $+125^{\circ}C$	0.08			%

LM4040-5.0

Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25$ °C. The grades A and B designate initial Reverse Breakdown Voltage tolerances of $\pm 0.1\%$ and $\pm 0.2\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040AIM3 LM4040AIZ Limits (Note 5)	LM4040BIM3 LM4040BIZ LM4040BIM7 Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 100 μA	5.000			V
	Reverse Breakdown Voltage	I _R = 100 μA		±5.0	±10	mV (max)
	Tolerance (Note 6)			±38	±43	mV (max)
I _{RMIN}	Minimum Operating Current		54			μΑ
				74	74	μA (max)
				80	80	μA (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown	I _R = 10 mA	±30			ppm/°C
Voltage Temperature Coefficient (<i>Note 6</i>)	I _R = 1 mA	±20	±100	±100	ppm/°C (max)	
	Coefficient (Note 6)	I _R = 100 μA	±20			ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (<i>Note 7</i>)	I _{RMIN} ≤ I _R ≤ 1 mA	0.5			mV
				1.0	1.0	mV (max)
				1.4	1.4	mV (max)
		1 mA ≤ I _R ≤ 15 mA	3.5			mV
				8.0	8.0	mV (max)
				12.0	12.0	mV (max)
Z_R	Reverse Dynamic Impedance	$I_R = 1 \text{ mA, f} = 120 \text{ Hz,}$	0.5			Ω
		$I_{AC} = 0.1 I_{R}$		1.1	1.1	Ω (max)
e _N	Wideband Noise	I _R = 100 μA	80			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				
ΔV_R	Reverse Breakdown Voltage	t = 1000 hrs				
	Long Term Stability	$T = 25^{\circ}C \pm 0.1^{\circ}C$	120			ppm
		I _R = 100 μA				
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C$ to $+125^{\circ}C$	0.08			%

LM4040-5.0 Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}; all other limits T_A = T_J = 25°C. The grades C and D designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$ and $\pm 1.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CIM3 LM4040CIZ LM4040CIM7 Limits (Note 5)	LM4040DIM3 LM4040DIZ LM4040DIM7 Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 100 μA	5.000	,		V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	Ι _R = 100 μΑ		±25 ± 58	±50 ± 99	mV (max)
I _{RMIN}	Minimum Operating Current		54	±36	±99	mV (max) μΑ
HMIN	polaning canoni			74 80	79 85	μΑ (max) μΑ (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown Voltage Temperature Coefficient (<i>Note 6</i>)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 100 \mu \text{A}$	±30 ±20 ±20	±100	±150	ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (<i>Note 7</i>)	$I_{RMIN} \le I_R \le 1 \text{ mA}$ $1 \text{ mA} \le I_R \le 15 \text{ mA}$	3.5	1.0 1.4 8.0 12.0	1.3 1.8 10.0 15.0	mV mV (max) mV (max) mV mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz, I _{AC} = 0.1 I _B	0.5	1.1	1.5	Ω Ω (max)
e _N	Wideband Noise	$I_R = 100 \mu A$ 10 Hz $\leq f \leq 10 \text{ kHz}$	80			μV_{rms}
ΔV_R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs $T = 25^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$ $I_{R} = 100 \mu\text{A}$	120			ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C$ to $+125^{\circ}C$	0.08			%

LM4040-5.0 Electrical Characteristics (Extended Temperature Range) Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C and D designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$ and $\pm 1.0\%$, respectively.

			Typical	LM4040CEM3	LM4040DEM3	
Symbol	Parameter	Conditions		Limits	Limits	Units (Limit)
			(Note 4)	(Note 5)	(<i>Note 5</i>)	
V _R	Reverse Breakdown Voltage	I _R = 100 μA	5.000			V
	Reverse Breakdown Voltage	I _R = 100 μA		±25	±50	mV (max)
	Tolerance(Note 6)			±75	±125	mV (max)
I _{RMIN}	Minimum Operating Current		54			μΑ
				74	79	μA (max)
				83	88	μA (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown	I _R = 10 mA	±30			ppm/°C
	Voltage Temperature	I _R = 1 mA	±20	±100	±150	ppm/°C (max)
	Coefficient (Note 6)	I _R = 100 μA	±20			ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage	I _{RMIN} ≤ I _R ≤ 1 mA	0.5			mV
	Change with Operating			1.0	1.0	mV (max)
	Current Change (Note 7)			1.4	1.8	mV (max)
		1 mA ≤ I _R ≤ 15 mA	3.5			mV
				8.0	8.0	mV (max)
				12.0	15.0	mV (max)
Z_R	Reverse Dynamic Impedance	$I_R = 1 \text{ mA}, f = 120 \text{ Hz}, I_{AC} = 0.1$	0.5			Ω
		I _R		1.1	1.1	Ω (max)
e _N	Wideband Noise	I _R = 100 μA	80			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				
ΔV _R	Reverse Breakdown Voltage	t = 1000 hrs				
	Long Term Stability	T = 25°C ±0.1°C	120			ppm
		I _R = 100 μA				
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40$ °C to +125°C	0.08			%

LM4040-8.2 Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}; all other limits T_A = T_J = 25°C. The grades A and B designate initial Reverse Breakdown Voltage tolerances of $\pm 0.1\%$ and $\pm 0.2\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040AIM3 LM4040AIZ Limits (Note 5)	LM4040BIM3 LM4040BIZ Limits (<i>Note 5</i>)	Units (Limit)
$\overline{V_R}$	Reverse Breakdown Voltage	I _R = 150 μA	8.192			V
	Reverse Breakdown Voltage	I _R = 150 μA		±8.2	±16	mV (max)
	Tolerance (Note 6)			±61	±70	mV (max)
I _{RMIN}	Minimum Operating Current		67			μΑ
				91	91	μA (max)
				95	95	μA (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown	I _R = 10 mA	±40			ppm/°C
Voltage Temperature Coefficient(<i>Note 6</i>)	I _R = 1 mA	±20	±100	±100	ppm/°C (max)	
	Coefficient(Note 6)	I _R = 150 μA	±20			ppm/°C
$\Delta V_R/\Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (<i>Note 7</i>)	I _{RMIN} ≤ I _R ≤ 1 mA	0.6			mV
				1.3	1.3	mV (max)
				2.5	2.5	mV (max)
		1 mA ≤ I _R ≤ 15 mA	7.0			mV
				10.0	10.0	mV (max)
				18.0	18.0	mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz,	0.6			Ω
		$I_{AC} = 0.1 I_{R}$		1.5	1.5	Ω (max)
e _N	Wideband Noise	I _R = 150 μA	130			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				
ΔV_R	Reverse Breakdown Voltage	t = 1000 hrs				
	Long Term Stability	T = 25°C ±0.1°C	120			ppm
		I _R = 150 μA				
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C$ to $+125^{\circ}C$	0.08			%

LM4040-8.2 Electrical Characteristics (Industrial Temperature Range) Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C and D designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$ and $\pm 1.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CIM3 LM4040CIZ Limits (Note 5)	LM4040DIM3 LM4040DIZ Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 150 μA	8.192			V
	Reverse Breakdown Voltage	I _R = 150 μA		±41	±82	mV (max)
	Tolerance (Note 6)			±94	±162	mV (max)
I _{RMIN}	Minimum Operating Current		67			μΑ
				91	96	μA (max)
				95	100	μA (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown	I _R = 10 mA	±40			ppm/°C
	Voltage Temperature Coefficient (<i>Note 6</i>)	I _R = 1 mA	±20	±100	±150	ppm/°C (max)
		I _R = 150 μA	±20			ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating	I _{RMIN} ≤ I _R ≤ 1 mA	0.6			mV
				1.3	1.7	mV (max)
	Current Change (Note 7)			2.5	3.0	mV (max)
		1 mA ≤ I _R ≤ 15 mA	7.0			mV
				10.0	15.0	mV (max)
				18.0	24.0	mV (max)
Z _R	Reverse Dynamic Impedance	$I_R = 1 \text{ mA}, f = 120 \text{ Hz},$	0.6			Ω
		$I_{AC} = 0.1 I_{R}$		1.5	1.9	Ω (max)
e _N	Wideband Noise	I _R = 150 μA	130			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				
ΔV _R	Reverse Breakdown Voltage	t = 1000 hrs				
	Long Term Stability	T = 25°C ±0.1°C	120			ppm
		I _R = 150 μA				
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C$ to $+125^{\circ}C$	0.08			%

LM4040-10.0 Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}; all other limits T_A = T_J = 25°C. The grades A and B designate initial Reverse Breakdown Voltage tolerances of $\pm 0.1\%$ and $\pm 0.2\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040AIM3 LM4040AIZ Limits (Note 5)	LM4040BIM3 LM4040BIZ Limits (Note 5)	Units (Limit)
$\overline{V_R}$	Reverse Breakdown Voltage	I _R = 150 μA	10.00			V
	Reverse Breakdown Voltage	I _R = 150 μA		±10	±20	mV (max)
	Tolerance (Note 6)			±75	±85	mV (max)
I _{RMIN}	Minimum Operating Current		75			μΑ
				100	100	μA (max)
				103	103	μA (max)
$\Delta V_R/\Delta T$	Average Reverse Breakdown	I _R = 10 mA	±40			ppm/°C
Voltage Temperature Coefficient (<i>Note 6</i>)	· '	I _R = 1 mA	±20	±100	±100	ppm/°C (max)
	Coefficient (<i>Note 6</i>)	I _R = 150 μA	±20			ppm/°C
$\Delta V_R/\Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (<i>Note 7</i>)	I _{RMIN} ≤ I _R ≤ 1 mA	0.8			mV
				1.5	1.5	mV (max)
				3.5	3.5	mV (max)
		1 mA ≤ I _R ≤ 15 mA	8.0			mV
				12.0	12.0	mV (max)
				23.0	23.0	mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz,	0.7			Ω
		$I_{AC} = 0.1 I_{R}$		1.7	1.7	Ω (max)
e _N	Wideband Noise	I _R = 150 μA	180			μV_{rms}
		10 Hz ≤ f ≤ 10 kHz				
ΔV_{R}	Reverse Breakdown Voltage	t = 1000 hrs				
	Long Term Stability	T = 25°C ±0.1°C	120			ppm
		I _R = 150 μA				
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ}C$ to $+125^{\circ}C$	0.08			%

LM4040-10.0

Electrical Characteristics (Industrial Temperature Range)

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}$ C. The grades C and D designate initial Reverse Breakdown Voltage tolerances of $\pm 0.5\%$ and $\pm 1.0\%$, respectively.

Symbol	Parameter	Conditions	Typical (Note 4)	LM4040CIM3 LM4040CIZ Limits (Note 5)	LM4040DIM3 LM4040DIZ Limits (Note 5)	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 150 μA	10.00		, ,	V
	Reverse Breakdown Voltage Tolerance (<i>Note 6</i>)	I _R = 150 μA		±50 ±115	±100 ±198	mV (max) mV (max)
I _{RMIN}	Minimum Operating Current		75	100 103	110 113	μΑ μΑ (max) μΑ (max)
ΔV _R /ΔΤ	Average Reverse Breakdown Voltage Temperature Coefficient (<i>Note 6</i>)	$I_R = 10 \text{ mA}$ $I_R = 1 \text{ mA}$ $I_R = 150 \mu\text{A}$	±40 ±20 ±20	±100	±150	ppm/°C ppm/°C (max) ppm/°C
$\Delta V_R / \Delta I_R$	Reverse Breakdown Voltage Change with Operating Current Change (<i>Note 7</i>)	I _{RMIN} ≤ I _R ≤ 1 mA	0.8	1.5 3.5	2.0 4.0	mV mV (max) mV (max)
		1 mA ≤ I _R ≤ 15 mA	8.0	12.0 23.0	18.0 29.0	mV mV (max) mV (max)
Z _R	Reverse Dynamic Impedance	$I_R = 1 \text{ mA, } f = 120 \text{ Hz,}$ $I_{AC} = 0.1 I_R$	0.7	1.7	2.3	Ω Ω (max)
e _N	Wideband Noise	I _R = 150 μA 10 Hz ≤ f ≤ 10 kHz	180			μV_{rms}
ΔV_R	Reverse Breakdown Voltage Long Term Stability	t = 1000 hrs T = 25°C ±0.1°C $I_B = 150 \mu A$	120			ppm
V _{HYST}	Thermal Hysteresis (Note 8)	$\Delta T = -40^{\circ} \text{C to } +125^{\circ} \text{C}$	0.08			%

Electrical Characteristics(Notes)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is $PD_{max} = (T_{Jmax} - T_A)/\theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower. For the LM4040, $T_{Jmax} = 125^{\circ}$ C, and the typical thermal resistance (θ_{JA}) , when board mounted, is 326°C/W for the SOT-23 package, and 180°C/W with 0.4 lead length and 170°C/W with 0.125 lead length for the TO-92 package and 415°C/W for the SC70 Package.

Note 3: The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin.

Note 4: Typicals are at $T_J = 25^{\circ}$ C and represent most likely parametric norm.

Note 5: Limits are 100% production tested at 25°C. Limits over temperature are guaranteed through correlation using Statistical Quality Control (SQC) methods. The limits are used to calculate National's AOQL.

Note 6: The boldface (over-temperature) limit for Reverse Breakdown Voltage Tolerance is defined as the room temperature Reverse Breakdown Voltage Tolerance $\pm [(\Delta V_R/\Delta T)(\max\Delta T)(V_R)]$. Where, $\Delta V_R/\Delta T$ is the V_R temperature coefficient, $\max\Delta T$ is the maximum difference in temperature from the reference point of 25°C to T_{MIN} or T_{MAX} , and V_R is the reverse breakdown voltage. The total over-temperature tolerance for the different grades in the industrial temperature range where $\max\Delta T = 65^{\circ}C$ is shown below:

A-grade: $\pm 0.75\% = \pm 0.1\% \pm 100 \text{ ppm/}^{\circ}\text{C} \times 65^{\circ}\text{C}$ B-grade: $\pm 0.85\% = \pm 0.2\% \pm 100 \text{ ppm/}^{\circ}\text{C} \times 65^{\circ}\text{C}$ C-grade: $\pm 1.15\% = \pm 0.5\% \pm 100 \text{ ppm/}^{\circ}\text{C} \times 65^{\circ}\text{C}$ D-grade: $\pm 1.98\% = \pm 1.0\% \pm 150 \text{ ppm/}^{\circ}\text{C} \times 65^{\circ}\text{C}$ E-grade: $\pm 2.98\% = \pm 2.0\% \pm 150 \text{ ppm/}^{\circ}\text{C} \times 65^{\circ}\text{C}$

The total over-temperature tolerance for the different grades in the exteded temperature range where max $\Delta T = 100$ °C is shown below:

C-grade: $\pm 1.5\% = \pm 0.5\% \pm 100 \text{ ppm/}^{\circ}\text{C} \times 100^{\circ}\text{C}$ D-grade: $\pm 2.5\% = \pm 1.0\% \pm 150 \text{ ppm/}^{\circ}\text{C} \times 100^{\circ}\text{C}$ E-grade: $\pm 3.5\% = \pm 2.0\% \pm 150 \text{ ppm/}^{\circ}\text{C} \times 100^{\circ}\text{C}$

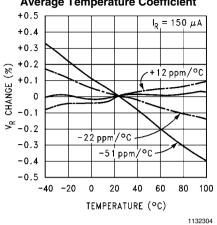
Therefore, as an example, the A-grade LM4040-2.5 has an over-temperature Reverse Breakdown Voltage tolerance of ±2.5V × 0.75% = ±19 mV.

Note 7: Load regulation is measured on pulse basis from no load to the specified load current. Output changes due to die temperature change must be taken into account separately.

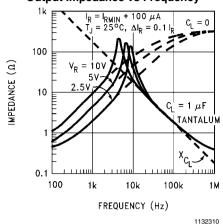
Note 8: Thermal hysteresis is defined as the difference in voltage measured at +25°C after cycling to temperature -40°C and the 25°C measurement after cycling to temperature +125°C.

Typical Performance Characteristics

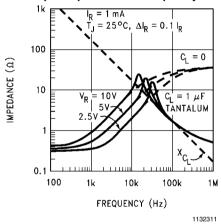
Temperature Drift for Different Average Temperature Coefficient



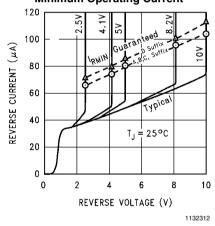
Output Impedance vs Frequency



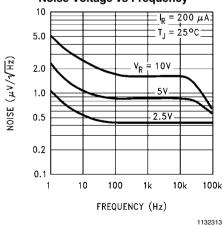
Output Impedance vs Frequency



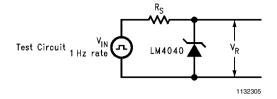
Reverse Characteristics and Minimum Operating Current

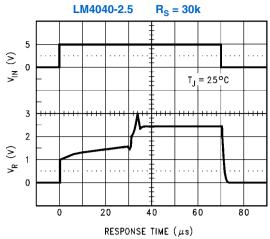


Noise Voltage vs Frequency

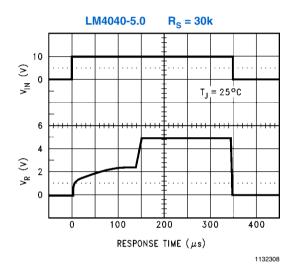


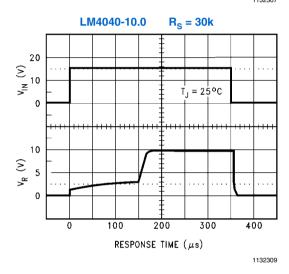
Start-Up Characteristics



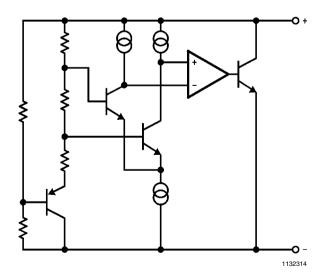


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Functional Block Diagram



Applications Information

The LM4040 is a precision micro-power curvature-corrected bandgap shunt voltage reference. For space critical applications, the LM4040 is available in the sub-miniature SOT-23 and SC70 surface-mount package. The LM4040 has been designed for stable operation without the need of an external capacitor connected between the "+" pin and the "-" pin. If, however, a bypass capacitor is used, the LM4040 remains stable. Reducing design effort is the availability of several fixed reverse breakdown voltages: 2.048V, 2.500V, 3.000V, 4.096V, 5.000V, 6.000, 8.192V, and 10.000V. The minimum operating current increases from 60 μA for the LM4040-2.048 and LM4040-2.5 to 100 μA for the LM4040-10.0. All versions have a maximum operating current of 15 mA.

LM4040s in the SOT-23 packages have a parasitic Schottky diode between pin 2 (–) and pin 3 (Die attach interface contact). Therefore, pin 3 of the SOT-23 package must be left floating or connected to pin 2.

LM4040s in the SC70 have a parasitic Schottky diode between pin 1 (–) and pin 2 (Die attach interface contact). Therefore, pin 2 must be left floating or connected to pin1.

The 4.096V version allows single +5V 12-bit ADCs or DACs to operate with an LSB equal to 1 mV. For 12-bit ADCs or DACs that operate on supplies of 10V or greater, the 8.192V version gives 2 mV per LSB.

The typical thermal hysteresis specification is defined as the change in +25°C voltage measured after thermal cycling. The

device is thermal cycled to temperature -40°C and then measured at 25°C. Next the device is thermal cycled to temperature +125°C and again measured at 25°C. The resulting $V_{\rm OUT}$ delta shift between the 25°C measurements is thermal hysteresis. Thermal hysteresis is common in precision references and is induced by thermal-mechanical package stress. Changes in environmental storage temperature, operating temperature and board mounting temperature are all factors that can contribute to thermal hysteresis.

In a conventional shunt regulator application (*Figure 1*) , an external series resistor (R_S) is connected between the supply voltage and the LM4040. R_S determines the current that flows through the load (I_L) and the LM4040 (I_Q). Since load current and supply voltage may vary, R_S should be small enough to supply at least the minimum acceptable I_Q to the LM4040 even when the supply voltage is at its minimum and the load current is at its maximum value. When the supply voltage is at its maximum and I_L is at its minimum, R_S should be large enough so that the current flowing through the LM4040 is less than 15 mA.

 $\rm R_S$ is determined by the supply voltage, $\rm (V_S),$ the load and operating current, ($\rm I_L$ and $\rm I_Q),$ and the LM4040's reverse breakdown voltage, $\rm V_R.$

$$R_S = \frac{V_S - V_R}{I_L + I_O}$$

Typical Applications

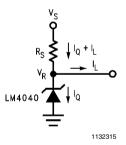
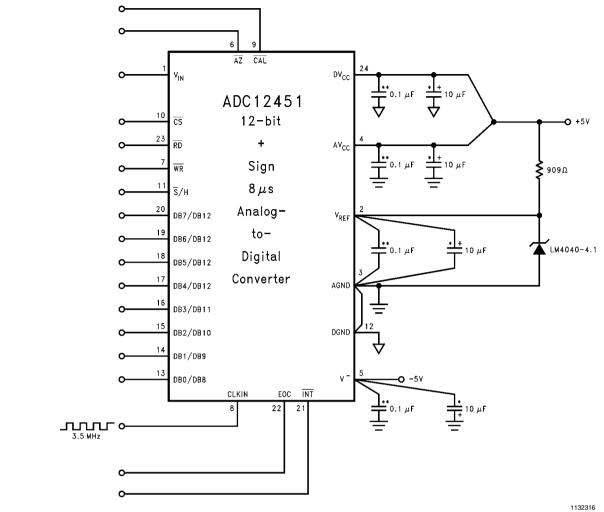


FIGURE 1. Shunt Regulator



**Ceramic monolithic

*Tantalum

FIGURE 2. LM4040-4.1's Nominal 4.096 breakdown voltage gives ADC12451 1 mV/LSB

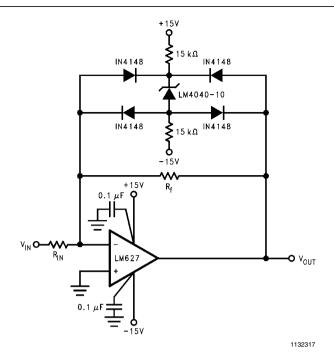


FIGURE 3. Bounded amplifier reduces saturation-induced delays and can prevent succeeding stage damage. Nominal clamping voltage is $\pm 11.5 \text{V}$ (LM4040's reverse breakdown voltage +2 diode V_{F}).

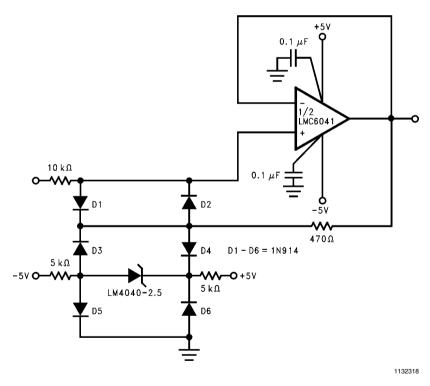


FIGURE 4. Protecting Op Amp input. The bounding voltage is $\pm 4V$ with the LM4040-2.5 (LM4040's reverse breakdown voltage + 3 diode V_F).

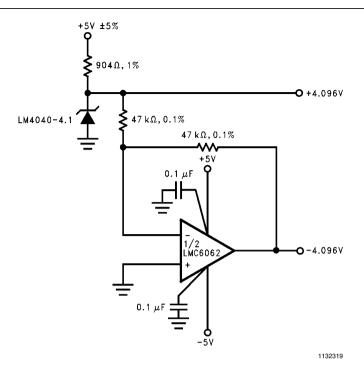


FIGURE 5. Precision ±4.096V Reference

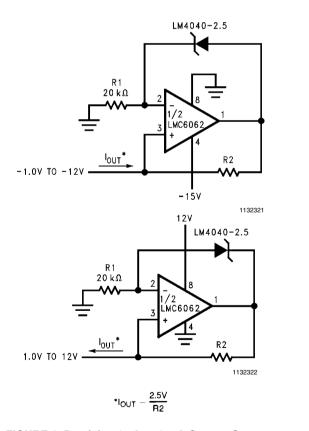
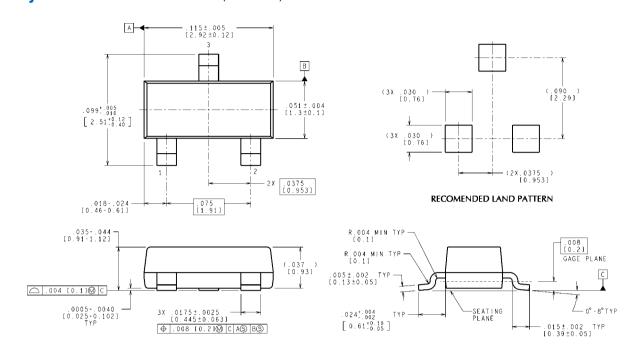


FIGURE 6. Precision 1 µA to 1 mA Current Sources

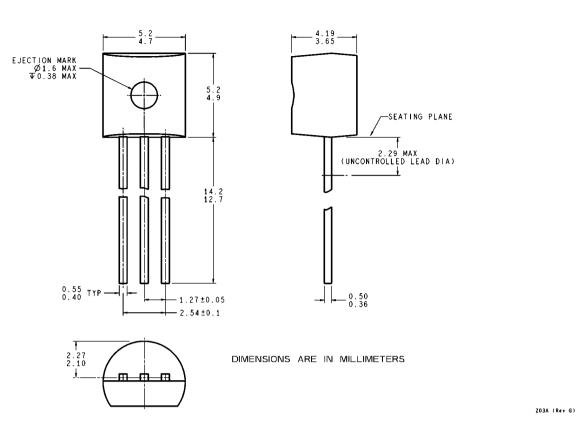
Physical Dimensions inches (millimeters) unless otherwise noted



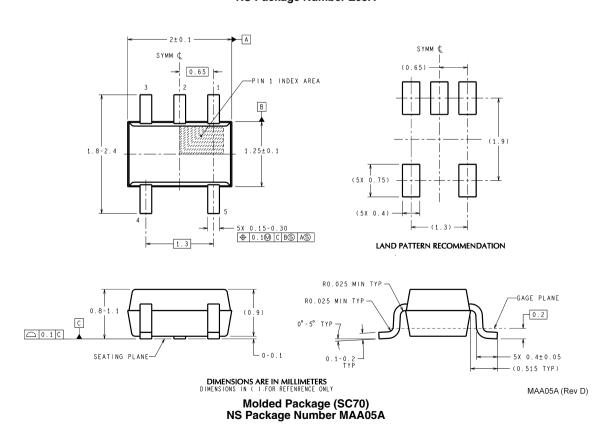
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MF03A (Rev B)

Plastic Surface Mount Package (M3) NS Package Number MF03A (JEDEC Registration TO-236AB)



Plastic Package (Z) NS Package Number Z03A



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